BYW29E series

GENERAL DESCRIPTION

Glass passivated high efficiency rugged rectifier diodes in a plastic envelope, featuring low forward voltage drop, ultra-fast recovery times and soft recovery characteristic. These devices can withstand reverse voltage transients and have guaranteed reverse surge and ESD capability. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

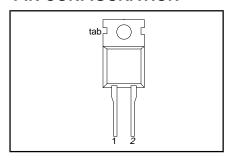
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V _{RRM}	BYW29E- Repetitive peak reverse voltage	100 100	150 150	200 200	V
V _F I _{F(AV)} t _{rr} I _{RRM}	Forward voltage Forward current Reverse recovery time Repetitive peak reverse current	0.895 8 25 0.2	0.895 8 25 0.2	0.895 8 25 0.2	V A ns A

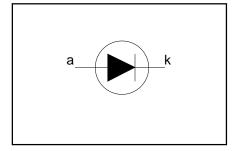
PINNING - TO220AC

PII	N	DESCRIPTION	
1		cathode (k)	
2		anode (a)	
tal	b	cathode (k)	

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT	
V _{RRM} V _{RWM} V _R	Repetitive peak reverse voltage Crest working reverse voltage Continuous reverse voltage		1 1 1	-100 100 100 100	-150 150 150 150	-200 200 200 200	<<<
I _{F(AV)}	Average forward current ¹	square wave; δ = 0.5; $T_{mb} \le 128 ^{\circ}\text{C}$ sinusoidal; a = 1.57;	-		8		А
١.	DMC forward assessed	$T_{mb} \le 130 ^{\circ}C$	-		7.3		Ă
I _{F(RMS)} I _{FRM}	RMS forward current Repetitive peak forward current	t = 25 μs; δ = 0.5; $T_{mb} \le 128 ^{\circ}C$	-		11.3 16		A A
I _{FSM}	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; with reapplied	-		80 88		A A
l ² t	I ² t for fusing	$ \begin{vmatrix} V_{\text{RWM(max)}} \\ t = 10 \text{ ms} \end{vmatrix} $	-		32		A ² s
I _{RRM}	Repetitive peak reverse current		-		0.2		A
I _{RSM}	Non-repetitive peak reverse current	t _p = 100 μs	-		0.2		A
${\mathsf T}_{stg} \atop {\mathsf T}_{\mathsf j}$	Storage temperature Operating junction temperature		-40 -		150 150		°C °C

¹ Neglecting switching and reverse current losses

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ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _c	J	Human body model; C = 250 pF; R = 1.5 kΩ	-	8	kV

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		-	-	2.7	K/W
R _{th j-a}		in free air	-	60	-	K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

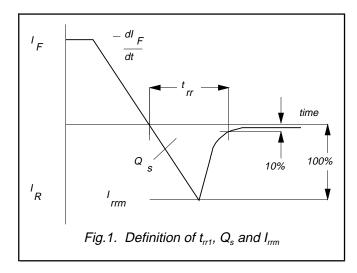
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	$I_F = 8 \text{ A}; T_i = 150^{\circ}\text{C}$	-	0.80	0.895	V
	_	$I_F = 8 \text{ A}$	-	0.92	1.05	V
		$I_{\rm F} = 20 \text{ A}$	-	1.1	1.3	V
I _R	Reverse current	$\dot{V}_R = V_{RWM}$; $T_i = 100 ^{\circ}C$	-	0.2	0.6	mΑ
		$V_R = V_{RWM}$	-	2	10	μΑ

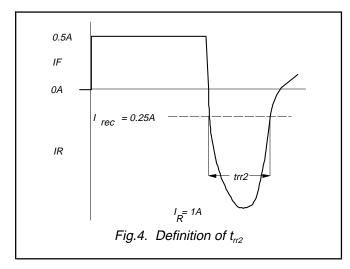
DYNAMIC CHARACTERISTICS

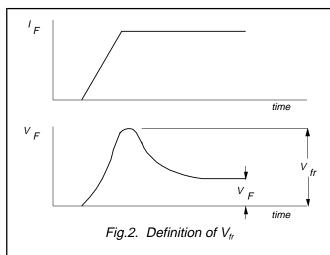
 $T_j = 25$ °C unless otherwise stated

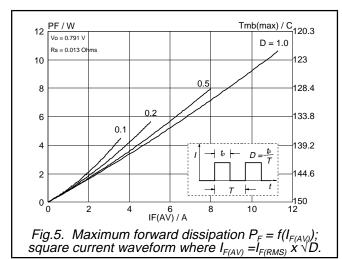
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Qs		$I_F = 2 \text{ A}; V_R \ge 30 \text{ V}; -dI_F/dt = 20 \text{ A}/\mu\text{s}$	-	4 20	11 25	nC
L _{rr1}	Reverse recovery time	$I_F = 1 \text{ A}; V_R \ge 30 \text{ V};$ $-dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	20	∠5	ns
$V_{\rm fr}$	Reverse recovery time Forward recovery voltage	$ I_F = 0.5 \text{ A to } I_R = 1 \text{ A; } I_{rec} = 0.25 \text{ A}$ $ I_F = 1 \text{ A; } dI_F/dt = 10 \text{ A/}\mu\text{s}$	-	15 1	20 -	ns V

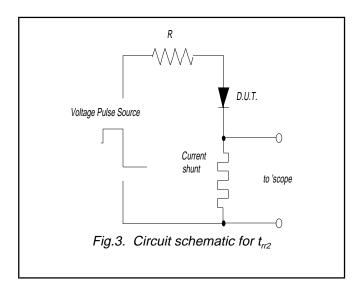
BYW29E series

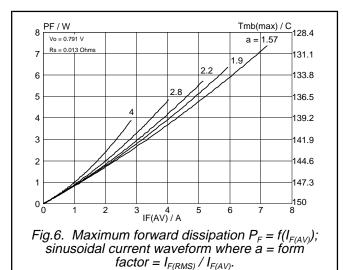




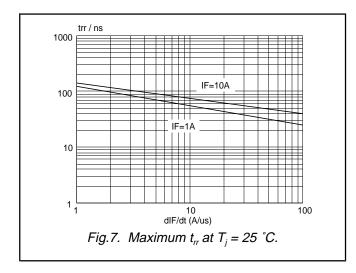


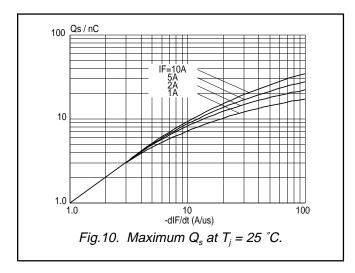


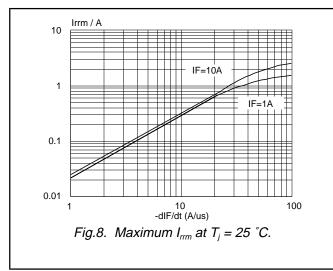


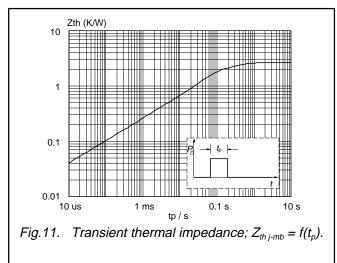


BYW29E series









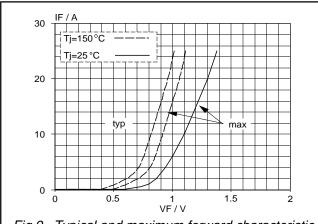
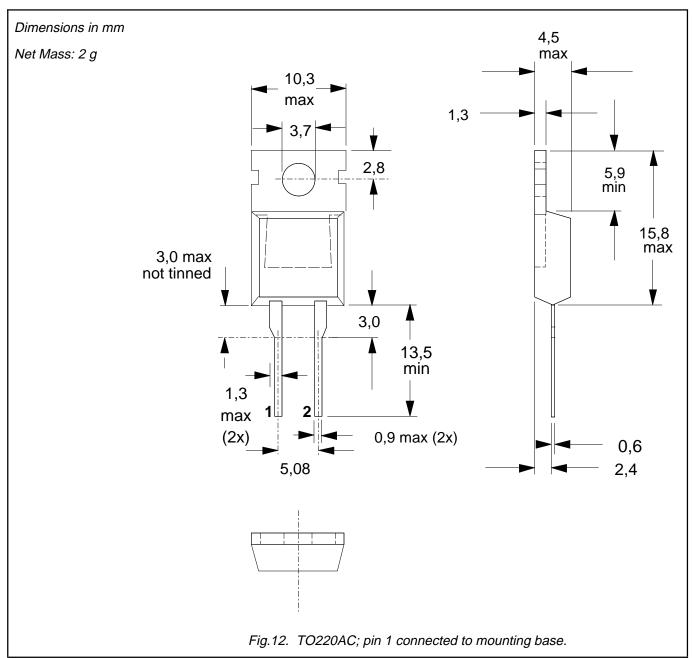


Fig.9. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

BYW29E series

MECHANICAL DATA



- Accessories supplied on request: refer to mounting instructions for TO220 envelopes.
 Epoxy meets UL94 V0 at 1/8".

Rectifier	diodes
ultrafast,	rugged

BYW29E series

DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Product specification	This data sheet contains final product specifications.				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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